

CDM3-800

**SURFACE MOUNT SILICON
N-CHANNEL
POWER MOSFET
3.0 AMP, 800 VOLT**



www.centralsemi.com

DESCRIPTION:

The CENTRAL SEMICONDUCTOR CDM3-800 is a 800 volt N-Channel MOSFET designed for high voltage, fast switching applications such as Power Factor Correction (PFC), lighting and power inverters. This MOSFET combines high voltage capability with low $r_{DS(ON)}$, low threshold voltage, and low gate charge for optimal efficiency.



DPAK CASE

APPLICATIONS:

- Power Factor Correction
- Alternative energy inverters
- Solid State Lighting (SSL)

FEATURES:

- High voltage capability ($V_{DS}=800V$)
- Low gate charge ($Q_{g(tot)}=11.3nC$ TYP)
- Low $r_{DS(ON)}$ (3.8 Ω TYP)

MAXIMUM RATINGS: ($T_C=25^\circ\text{C}$ unless otherwise noted)

	SYMBOL		UNITS
Drain-Source Voltage	V_{DS}	800	V
Gate-Source Voltage	V_{GS}	30	V
Continuous Drain Current (Steady State)	I_D	3.0	A
Maximum Pulsed Drain Current, $t_p=10\mu\text{s}$	I_{DM}	12	A
Continuous Source Current (Body Diode)	I_S	3.0	A
Maximum Pulsed Source Current (Body Diode)	I_{SM}	12	A
Single Pulse Avalanche Energy (Note 1)	E_{AS}	173	mJ
Power Dissipation	P_D	80	W
Operating and Storage Junction Temperature	T_J, T_{stg}	-55 to +150	$^\circ\text{C}$
Thermal Resistance	Θ_{JC}	1.56	$^\circ\text{C}/\text{W}$
Thermal Resistance	Θ_{JA}	110	$^\circ\text{C}/\text{W}$

Note 1: $L=30\text{mH}$, $I_{AS}=3.15\text{A}$, $V_{DD}=100\text{V}$, $R_G=25\Omega$, Initial $T_J=25^\circ\text{C}$

ELECTRICAL CHARACTERISTICS: ($T_C=25^\circ\text{C}$ unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
I_{GSSF}, I_{GSSR}	$V_{GS}=30\text{V}, V_{DS}=0$		10	100	nA
I_{DSS}	$V_{DS}=800\text{V}, V_{GS}=0$		0.08	1.0	μA
BV_{DSS}	$V_{GS}=0, I_D=250\mu\text{A}$	800			V
$V_{GS(th)}$	$V_{GS}=V_{DS}, I_D=250\mu\text{A}$	2.0	3.0	4.0	V
V_{SD}	$V_{GS}=0, I_S=3.0\text{A}$		0.98	1.4	V
$r_{DS(ON)}$	$V_{GS}=10\text{V}, I_D=1.5\text{A}$		3.8	4.8	Ω
C_{rss}	$V_{DS}=25\text{V}, V_{GS}=0, f=1.0\text{MHz}$		1.5		pF
C_{iss}	$V_{DS}=25\text{V}, V_{GS}=0, f=1.0\text{MHz}$		415		pF
C_{oss}	$V_{DS}=25\text{V}, V_{GS}=0, f=1.0\text{MHz}$		44		pF

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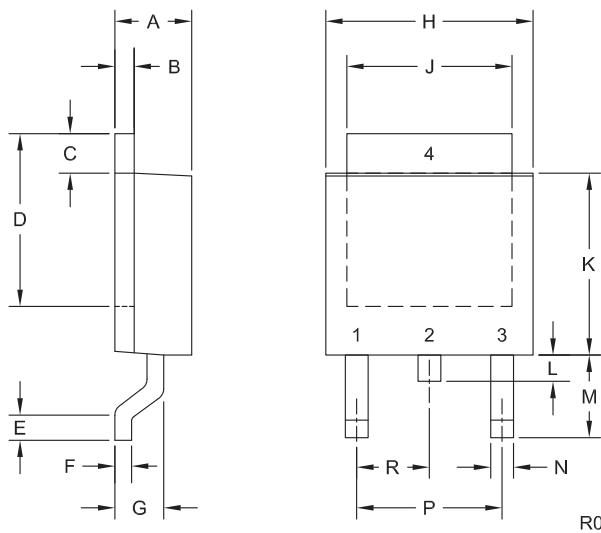


ELECTRICAL CHARACTERISTICS - Continued: ($T_C=25^\circ\text{C}$ unless otherwise noted)

SYMBOL	TEST CONDITIONS	TYP	UNITS
$Q_g(\text{tot})$	$V_{DS}=640\text{V}$, $V_{GS}=10\text{V}$, $I_D=3.0\text{A}$ (Note 2)	11.3	nC
Q_{gs}	$V_{DS}=640\text{V}$, $V_{GS}=10\text{V}$, $I_D=3.0\text{A}$ (Note 2)	2.55	nC
Q_{gd}	$V_{DS}=640\text{V}$, $V_{GS}=10\text{V}$, $I_D=3.0\text{A}$ (Note 2)	5.28	nC
$t_{d(\text{on})}$	$V_{DD}=400\text{V}$, $I_D=3.0\text{A}$, $R_G=25\Omega$ (Note 2)	10	ns
t_r	$V_{DD}=400\text{V}$, $I_D=3.0\text{A}$, $R_G=25\Omega$ (Note 2)	23	ns
$t_{d(\text{off})}$	$V_{DD}=400\text{V}$, $I_D=3.0\text{A}$, $R_G=25\Omega$ (Note 2)	25	ns
t_f	$V_{DD}=400\text{V}$, $I_D=3.0\text{A}$, $R_G=25\Omega$ (Note 2)	25	ns
t_{rr}	$V_{GS}=0$, $I_S=3.0\text{A}$, $dI/dt=100\text{A}/\mu\text{s}$ (Note 2)	437	ns
Q_{rr}	$V_{GS}=0$, $I_S=3.0\text{A}$, $dI/dt=100\text{A}/\mu\text{s}$ (Note 2)	1.68	μC

Note 2: Pulse Width $\leq 300\mu\text{s}$, Duty Cycle $\leq 2\%$

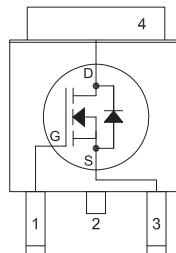
DPAK CASE - MECHANICAL OUTLINE



SYMBOL	DIMENSIONS		INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX	MIN	MAX
A	0.083	0.108	2.10	2.75		
B	0.016	0.032	0.40	0.81		
C	0.035	0.063	0.89	1.60		
D	0.203	0.228	5.15	5.79		
E	0.020	-	0.51	-		
F	0.018	0.024	0.45	0.60		
G	0.051	0.071	1.30	1.80		
H	0.248	0.268	6.30	6.81		
J	0.197	0.217	5.00	5.50		
K	0.209	0.245	5.30	6.22		
L	0.025	0.040	0.64	1.02		
M	0.090	0.115	2.30	2.91		
N	0.012	0.045	0.30	1.14		
P	0.180		4.60			
R	0.090		2.30			

DPAK (REV: R0)

PIN CONFIGURATION



LEAD CODE:

- 1) Gate
 - 2) Drain
 - 3) Source
 - 4) Drain
- Pin 2 is common to the tab (4)

MARKING: FULL PART NUMBER

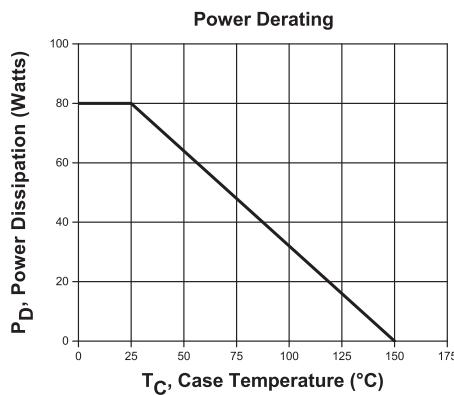
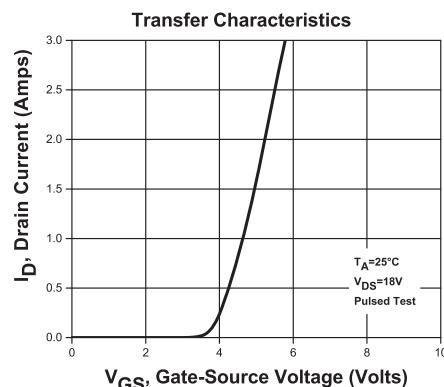
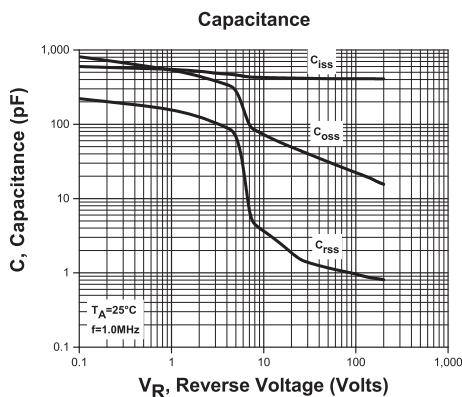
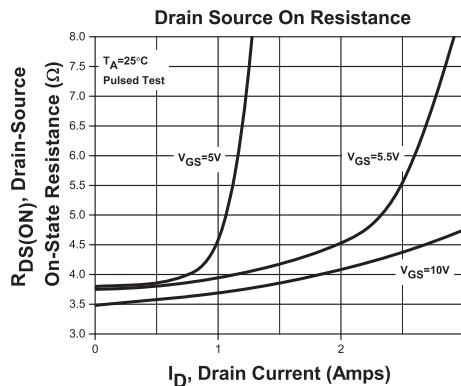
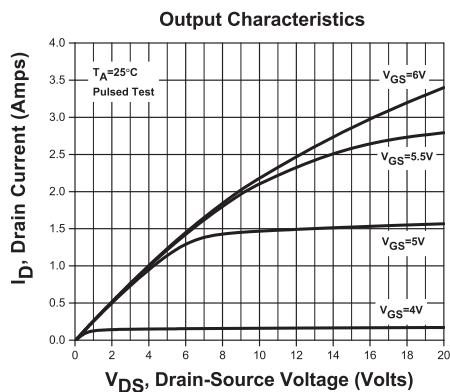
R1 (13-May 2015)

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TYPICAL ELECTRICAL CHARACTERISTICS



R1 (13-May 2015)

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PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- Inventory bonding
- Consolidated shipping options
- Custom bar coding for shipments
- Custom product packing

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free quick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- Custom electrical curves
- Environmental regulation compliance
- Customer specific screening
- Up-screening capabilities
- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- Application and design sample kits
- Custom product and package development

REQUESTING PRODUCT PLATING

1. If requesting Tin/Lead plated devices, add the suffix " TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
2. If requesting Lead (Pb) Free plated devices, add the suffix " PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

CONTACT US

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